

# Dual Switching Diode Common Anode

## BAW56L, SBAW56L

### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS (EACH DIODE)

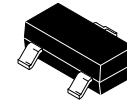
| Rating                                                                  | Symbol    | Value                            | Unit |
|-------------------------------------------------------------------------|-----------|----------------------------------|------|
| Reverse Voltage                                                         | $V_R$     | 70                               | V    |
| Forward Current                                                         | $I_F$     | 200                              | mA   |
| Forward Surge Current<br>(60 Hz @ 1 cycle)                              | $I_{FSM}$ | 2.0                              | A    |
| Non-Repetitive Peak Forward Current<br>$t = 1 \mu s$ (Note 3)           | $I_{FSM}$ | 4.0                              | A    |
| Repetitive Peak Forward Current<br>Pulse Wave = 1 sec, Duty Cycle = 66% | $I_{FRM}$ | 500                              | mA   |
| ESD Rating: Human Body Model<br>Machine Model<br>Charged Device Model   | ESD       | Class 3A<br>Class M4<br>Class C3 |      |

### THERMAL CHARACTERISTICS

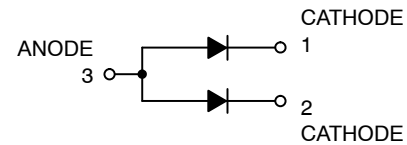
| Characteristic                                                                                             | Symbol          | Max            | Unit                 |
|------------------------------------------------------------------------------------------------------------|-----------------|----------------|----------------------|
| Total Device Dissipation FR-5 Board<br>(Note 1) $T_A = 25^\circ C$<br>Derate above $25^\circ C$            | $P_D$           | 225<br>1.8     | mW<br>mW/ $^\circ C$ |
| Thermal Resistance,<br>Junction-to-Ambient                                                                 | $R_{\theta JA}$ | 556            | $^\circ C/W$         |
| Total Device Dissipation<br>Alumina Substrate,<br>(Note 2) $T_A = 25^\circ C$<br>Derate above $25^\circ C$ | $P_D$           | 300<br>2.4     | mW<br>mW/ $^\circ C$ |
| Thermal Resistance,<br>Junction-to-Ambient                                                                 | $R_{\theta JA}$ | 417            | $^\circ C/W$         |
| Junction and Storage Temperature                                                                           | $T_J, T_{stg}$  | -55 to<br>+150 | $^\circ C$           |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

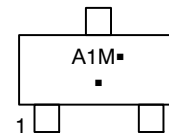
- FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
- Square Wave;  $T_J = 25^\circ C$ .



SOT-23 (TO-236)  
CASE 318  
STYLE 12



### MARKING DIAGRAM



A1 = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### ORDERING INFORMATION

| Device     | Package             | Shipping†               |
|------------|---------------------|-------------------------|
| BAW56LT1G  | SOT-23<br>(Pb-Free) | 3,000 /<br>Tape & Reel  |
| SBAW56LT1G | SOT-23<br>(Pb-Free) | 3,000 /<br>Tape & Reel  |
| BAW56LT3G  | SOT-23<br>(Pb-Free) | 10,000 /<br>Tape & Reel |
| SBAW56LT3G | SOT-23<br>(Pb-Free) | 10,000 /<br>Tape & Reel |

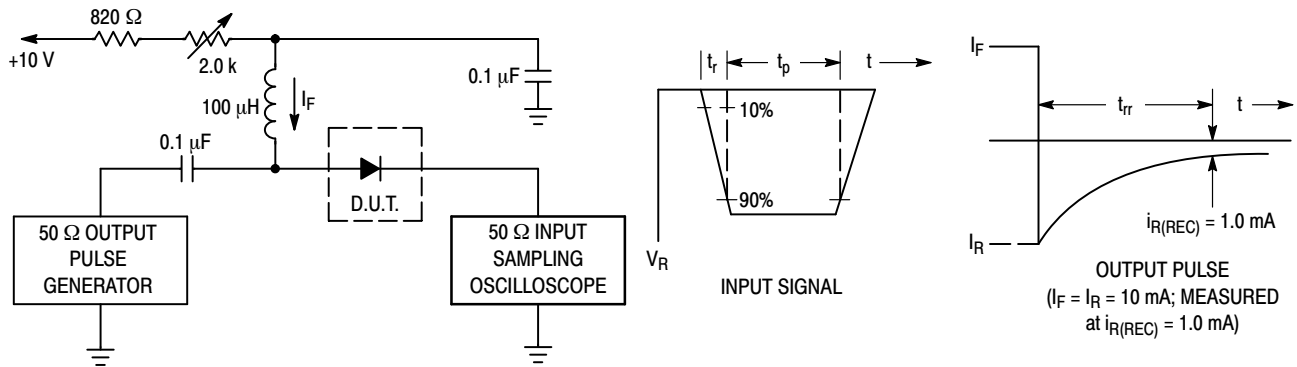
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# BAW56L, SBAW56L

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (Each Diode)

| Characteristic                                                                                                                                                              | Symbol     | Min              | Max                        | Unit          |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|------------------|----------------------------|---------------|
| Reverse Breakdown Voltage<br>( $I_{(BR)} = 100\ \mu\text{A}$ )                                                                                                              | $V_{(BR)}$ | 70               | –                          | V             |
| Reverse Voltage Leakage Current<br>( $V_R = 25\ \text{V}$ , $T_J = 150^\circ\text{C}$ )<br>( $V_R = 70\ \text{V}$ )<br>( $V_R = 70\ \text{V}$ , $T_J = 150^\circ\text{C}$ ) | $I_R$      | –<br>–<br>–      | 30<br>2.5<br>50            | $\mu\text{A}$ |
| Diode Capacitance<br>( $V_R = 0\ \text{V}$ , $f = 1.0\ \text{MHz}$ )                                                                                                        | $C_D$      | –                | 2.0                        | pF            |
| Forward Voltage<br>( $I_F = 1.0\ \text{mA}$ )<br>( $I_F = 10\ \text{mA}$ )<br>( $I_F = 50\ \text{mA}$ )<br>( $I_F = 150\ \text{mA}$ )                                       | $V_F$      | –<br>–<br>–<br>– | 715<br>855<br>1000<br>1250 | mV            |
| Reverse Recovery Time<br>( $I_F = I_R = 10\ \text{mA}$ , $I_{R(REC)} = 1.0\ \text{mA}$ ) (Figure 1) $R_L = 100\ \Omega$                                                     | $t_{rr}$   | –                | 6.0                        | ns            |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10 mA.  
2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10 mA.  
3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

# BAW56L, SBAW56L

## Curves Applicable to Each Cathode

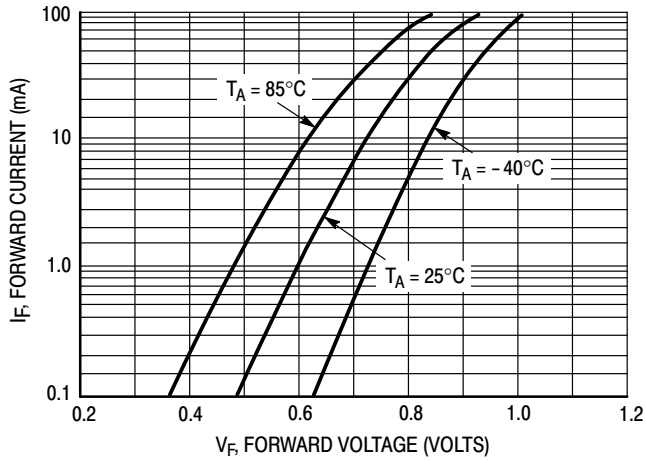


Figure 2. Forward Voltage

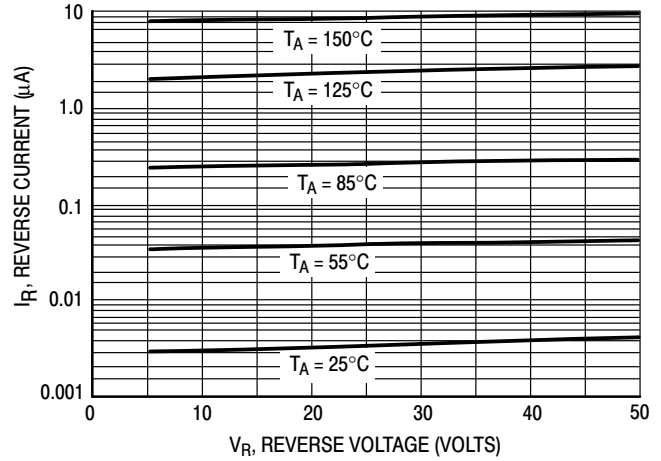


Figure 3. Leakage Current

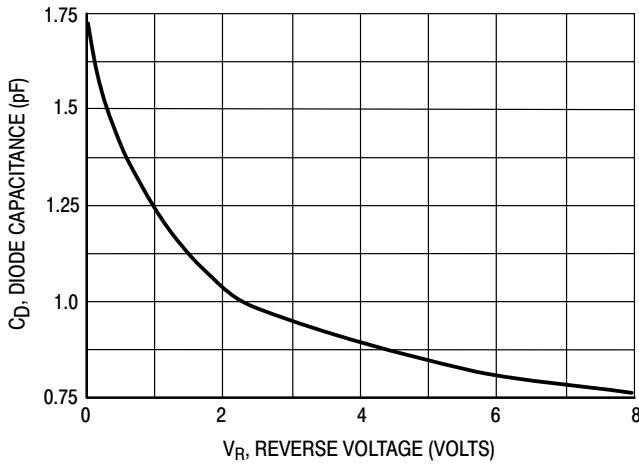


Figure 4. Capacitance

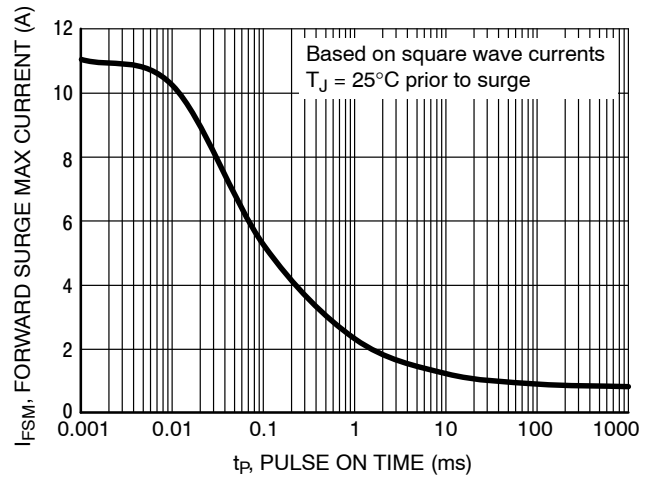


Figure 5. Forward Surge Current



SCALE 4:1

**SOT-23 (TO-236) 2.90x1.30x1.00 1.90P**  
CASE 318  
ISSUE AU

DATE 14 AUG 2024



| MILLIMETERS |      |      |      |
|-------------|------|------|------|
| DIM         | MIN  | NOM  | MAX  |
| A           | 0.89 | 1.00 | 1.11 |
| A1          | 0.01 | 0.06 | 0.10 |
| b           | 0.37 | 0.44 | 0.50 |
| c           | 0.08 | 0.14 | 0.20 |
| D           | 2.80 | 2.90 | 3.04 |
| E           | 1.20 | 1.30 | 1.40 |
| e           | 1.78 | 1.90 | 2.04 |
| L           | 0.30 | 0.43 | 0.55 |
| L1          | 0.35 | 0.54 | 0.69 |
| HE          | 2.10 | 2.40 | 2.64 |
| T           | 0°   | ---  | 10°  |

## NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

**GENERIC MARKING DIAGRAM\***


XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.


**RECOMMENDED MOUNTING FOOTPRINT**

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**STYLES ON PAGE 2**

|                         |                                             |                                                                                                                                                                                     |
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|                                                         |                                                       |                                                             |                                                             |                                                             |                                                             |
|---------------------------------------------------------|-------------------------------------------------------|-------------------------------------------------------------|-------------------------------------------------------------|-------------------------------------------------------------|-------------------------------------------------------------|
| STYLE 1 THRU 5:<br>CANCELLED                            | STYLE 6:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 7:<br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR       | STYLE 8:<br>PIN 1. ANODE<br>2. NO CONNECTION<br>3. CATHODE  |                                                             |                                                             |
| STYLE 9:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE      | STYLE 10:<br>PIN 1. DRAIN<br>2. SOURCE<br>3. GATE     | STYLE 11:<br>PIN 1. ANODE<br>2. CATHODE<br>3. CATHODE-ANODE | STYLE 12:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. ANODE       | STYLE 13:<br>PIN 1. SOURCE<br>2. DRAIN<br>3. GATE           | STYLE 14:<br>PIN 1. CATHODE<br>2. GATE<br>3. ANODE          |
| STYLE 15:<br>PIN 1. GATE<br>2. CATHODE<br>3. ANODE      | STYLE 16:<br>PIN 1. ANODE<br>2. CATHODE<br>3. CATHODE | STYLE 17:<br>PIN 1. NO CONNECTION<br>2. ANODE<br>3. CATHODE | STYLE 18:<br>PIN 1. NO CONNECTION<br>2. CATHODE<br>3. ANODE | STYLE 19:<br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE-ANODE | STYLE 20:<br>PIN 1. CATHODE<br>2. ANODE<br>3. GATE          |
| STYLE 21:<br>PIN 1. GATE<br>2. SOURCE<br>3. DRAIN       | STYLE 22:<br>PIN 1. RETURN<br>2. OUTPUT<br>3. INPUT   | STYLE 23:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE         | STYLE 24:<br>PIN 1. GATE<br>2. DRAIN<br>3. SOURCE           | STYLE 25:<br>PIN 1. ANODE<br>2. CATHODE<br>3. GATE          | STYLE 26:<br>PIN 1. CATHODE<br>2. ANODE<br>3. NO CONNECTION |
| STYLE 27:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE | STYLE 28:<br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE     |                                                             |                                                             |                                                             |                                                             |

|                  |                                      |                                                                                                                                                                                     |
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